

# first-principles electronic structure calculations for the solid state

some remarks



# first-principles calculations

most of the techniques used for molecules can also be applied to the solid state: DFT, HF, MBPT, CC

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$$E[n] = T[n] + \int \sum_{l} \frac{Z_{l}n(\mathbf{r})}{|\mathbf{r} - \mathbf{R}_{l}|} dr + \frac{1}{2} \iint \frac{n(\mathbf{r})n(\mathbf{r}')}{|\mathbf{r} - \mathbf{r}'|} d\mathbf{r} d\mathbf{r}' + E_{xc}[n]$$
charge density  $n(\mathbf{r}) = \sum_{n,\mathbf{k}} |\psi_{n,\mathbf{k}}(\mathbf{r})|^{2}$ 
needs a Brillouin zone integration
$$\text{metals need a dense } \mathbf{k}\text{-point grid}$$
self-consistency:
$$\text{metals converge slowly}$$

$$\text{magnetic metals even more so}$$

### the work horse: Density Functional Theory (DFT)

formation energies / heats of formation covalent/ionic bonding calculated with DFT/GGA (PBE) are typically accurate on a scale of 0.1 eV (10 kJ/mol)



van Setten et al., JPCC 111, 9592 (2007); PRB 72, 073107 (2005)

### Density Functional Theory (DFT)

### weak interactions need a van der Waals functional



## Density Functional Theory (DFT)

#### spectrum obtained from DFT/GGA (LDA) is not so impressive



## Hartree-Fock (HF)

HF computationally more expensive than DFT: 1-2 orders of magnitude



HF total energies are worse than DFT

the spectrum obtained from HF

is even less impressive

exp:. Ge semiconductor with band gap 0.7 eV HF: Ge insulator with band gap 4.2 eV band dispersions unreasonable ~50% too wide

### Hartree-Fock (HF): from bad to worse

### For metals the spectrum obtained from HF is a disaster

e.g. homogeneous electron gas (jellium) free electron spectrum ≈ MBPT



metals: electrons with energy E  $\approx$  E\_F are doing the conduction

### Electron correlations

truncated correlated methods don't work well for extended systems



infinite summation methods work



all these methods are computationally very expensive